



## ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-45	-	-	V	$I_D=-1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	-1	$\mu A$	$V_{DS}=-45V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	-1.0	-	-2.5	V	$V_{DS}=-10V, I_D=-1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	-	330	460	m $\Omega$	$I_D=-1A, V_{GS}=-10V$
		-	450	630		$I_D=-0.5A, V_{GS}=-4.5V$
		-	490	690		$I_D=-0.5A, V_{GS}=-4V$
Forward transfer admittance	$ Y_{fs} $	1	-	-	S	$I_D=-1A, V_{DS}=-10V$
Input capacitance	$C_{ISS}$	-	160	-	pF	$V_{DS}=-10V$
Output capacitance	$C_{OSS}$	-	40	-	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{RSS}$	-	17	-	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$ *	-	6	-	ns	$I_D=-0.5A, V_{DD}=-25V$
Rise time	$t_r$ *	-	4	-	ns	$V_{GS}=-10V$
Turn-off delay time	$t_{d(off)}$ *	-	18	-	ns	$R_L=50\Omega$
Fall time	$t_f$ *	-	6	-	ns	$R_G=10\Omega$
Total gate charge	$Q_g$ *	-	2.3	-	nC	$I_D=-1A$
Gate-source charge	$Q_{gs}$ *	-	0.9	-	nC	$V_{DD}=-25V$
Gate-drain charge	$Q_{gd}$ *	-	0.6	-	nC	$V_{GS}=-5V$

\*Pulsed

## ●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	$V_{SD}$ *	-	-	-1.2	V	$I_s=-1A, V_{GS}=0V$

\*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics ( I )

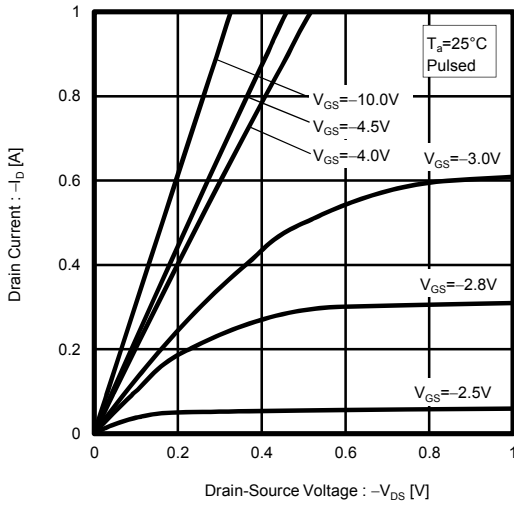


Fig.2 Typical Output Characteristics ( II )

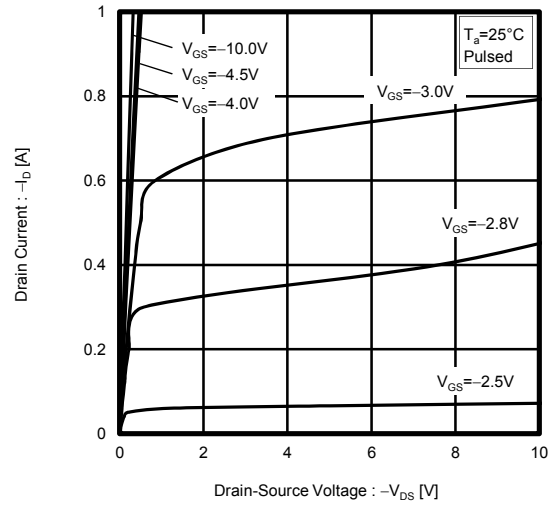


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

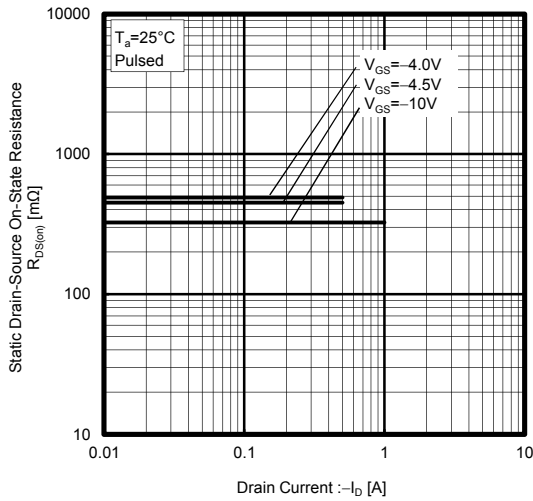


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

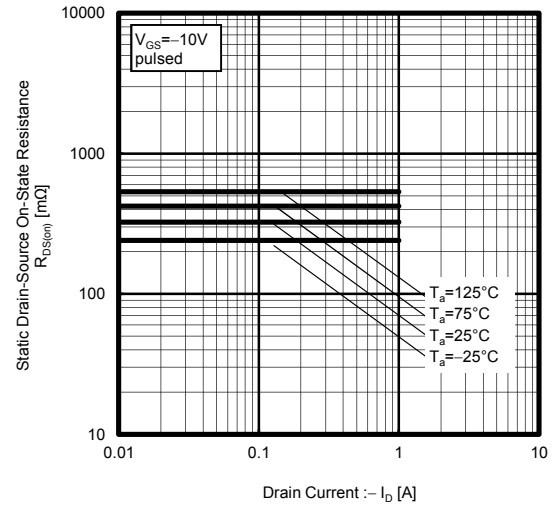


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

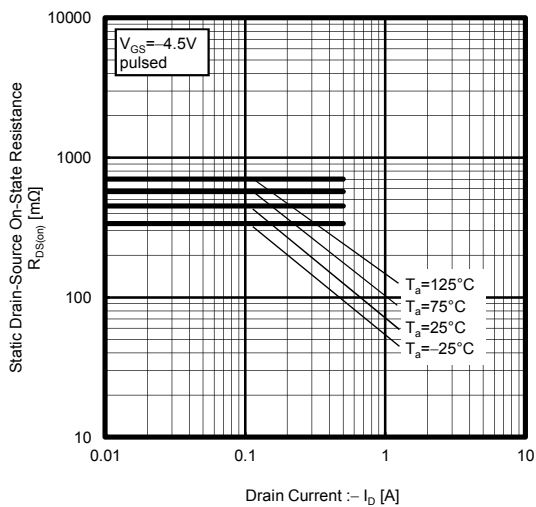


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

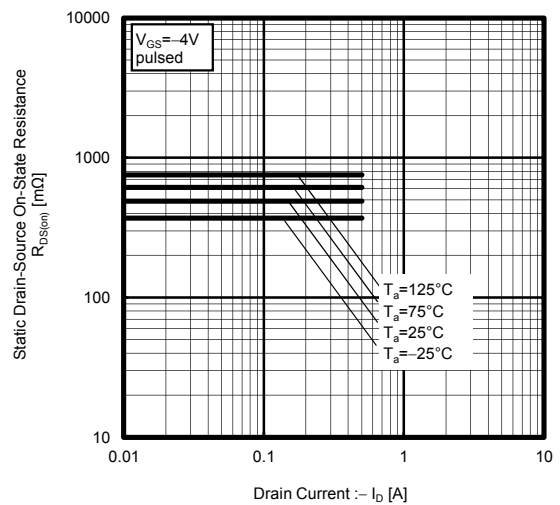


Fig.7 Forward Transfer Admittance vs. Drain Current

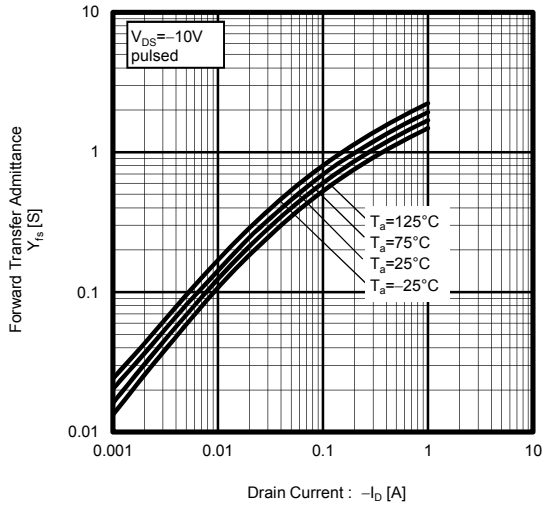


Fig.8 Typical Transfer Characteristics

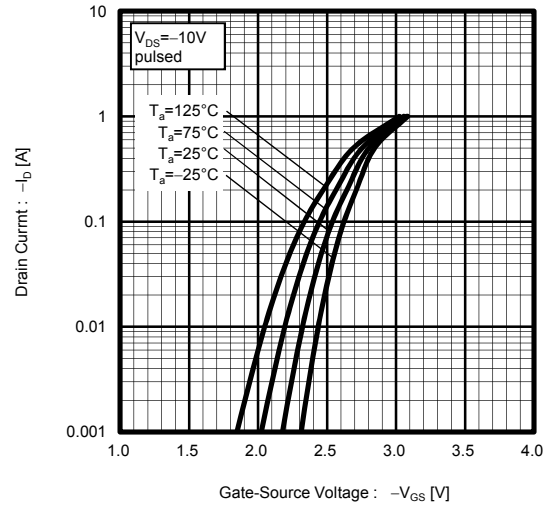


Fig.9 Source Current vs. Source-Drain Voltage

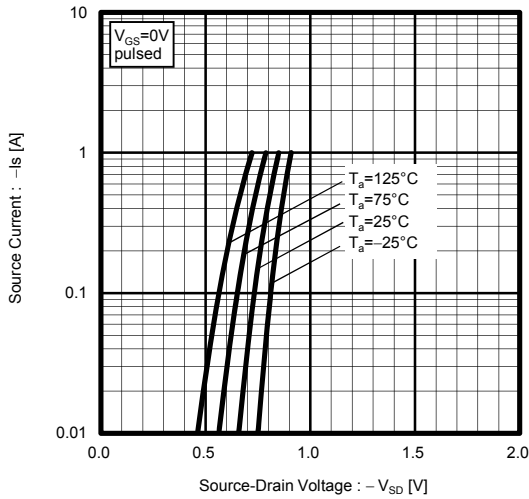


Fig.10 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

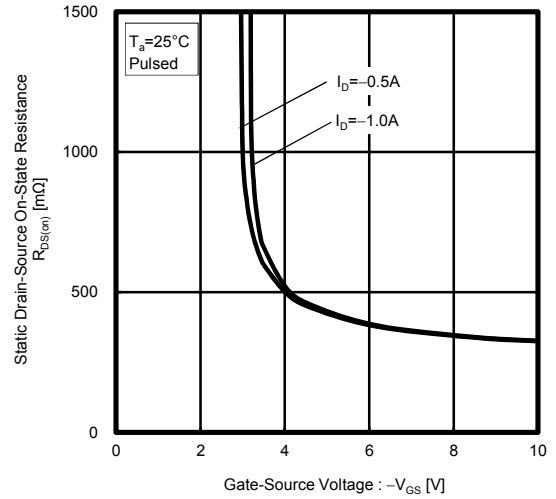


Fig.11 Switching Characteristics

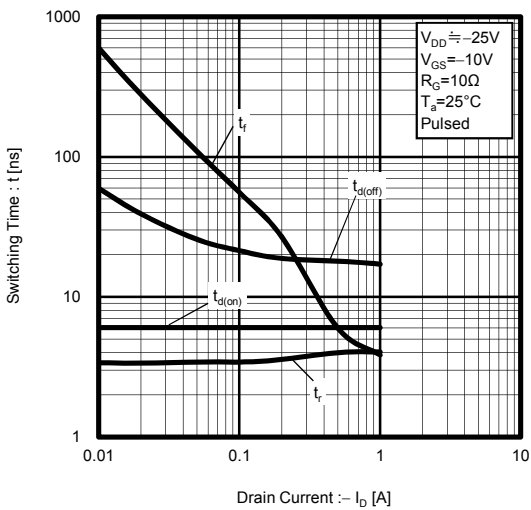


Fig.12 Dynamic Input Characteristics

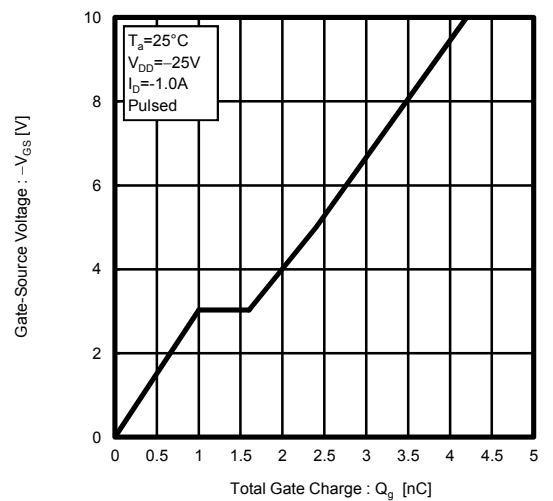


Fig.13 Typical Capacitance vs. Drain-Source Voltage

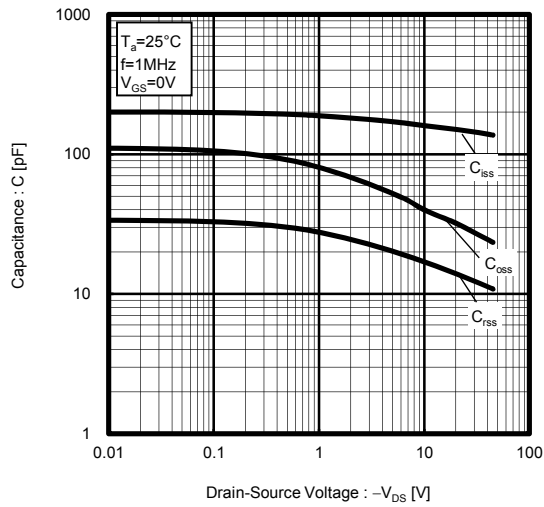


Fig.14 Maximum Safe Operating Area

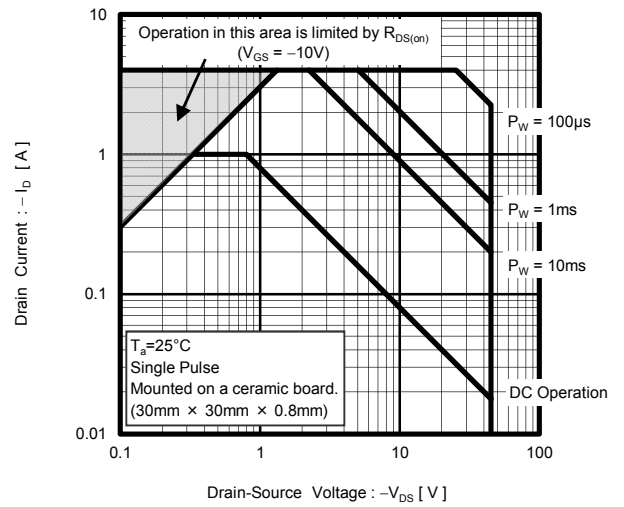
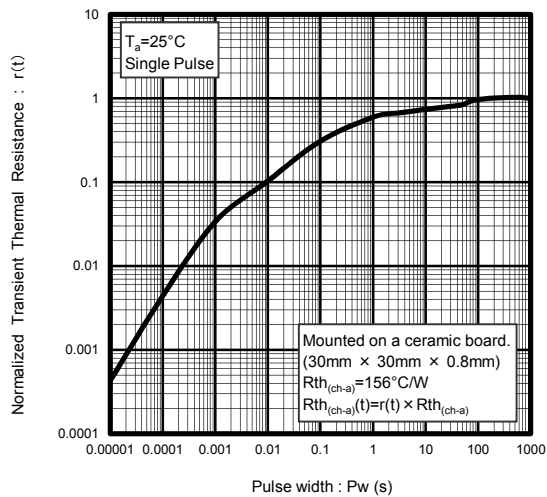


Fig.15 Normalized Transient Thermal Resistance v.s. Pulse Width



●Measurement circuits

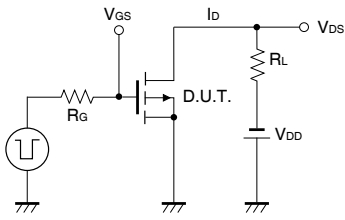


Fig.1-1 Switching Time Measurement Circuit

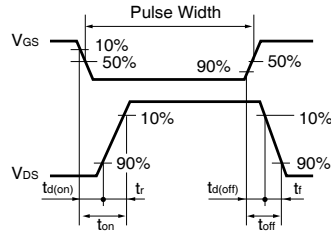


Fig.1-2 Switching Waveforms

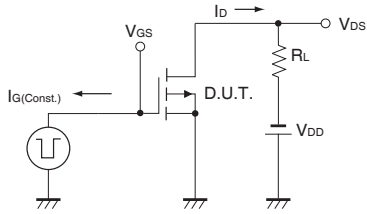


Fig.2-1 Gate Charge Measurement Circuit

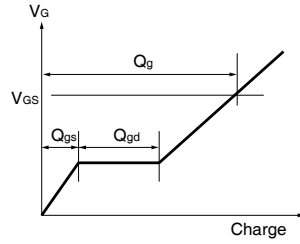


Fig.2-2 Gate Charge Waveform

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